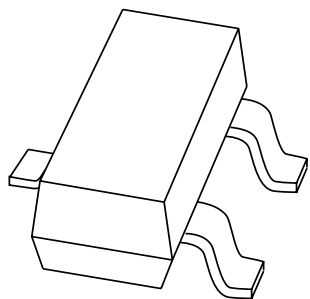


# DATA SHEET



## **BCV26; BCV46** PNP Darlington transistors

Product specification  
Supersedes data of September 1994  
File under Discrete Semiconductors, SC04

1997 Apr 23

## PNP Darlington transistors

## BCV26; BCV46

## FEATURES

- High current (max. 500 mA)
- Low voltage (max. 60 V)
- Very high DC current gain (min. 10000).

## APPLICATIONS

- Where very high amplification is required.

## DESCRIPTION

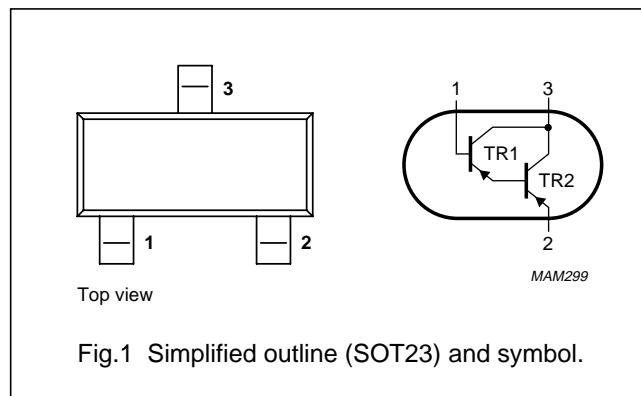
PNP Darlington transistor in a SOT23 plastic package.  
NPN complements: BCV27 and BCV47.

## MARKING

TYPE NUMBER	MARKING CODE
BCV26	FDp
BCV46	FEp

## PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



## QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter				
	BCV26		–	–	–40	V
	BCV46		–	–	–80	V
$V_{CES}$	collector-emitter voltage	$V_{BE} = 0$				
	BCV26		–	–	–30	V
	BCV46		–	–	–60	V
$I_C$	collector current (DC)		–	–	–500	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ }^\circ\text{C}$	–	–	250	mW
$h_{FE}$	DC current gain	$I_C = -10\text{ mA}; V_{CE} = -5\text{ V}$				
	BCV26		10000	–	–	
	BCV46		4000	–	–	
$f_T$	transition frequency	$I_C = -30\text{ mA}; V_{CE} = -5\text{ V}; f = 100\text{ MHz}$	–	220	–	MHz

## PNP Darlington transistors

## BCV26; BCV46

**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter			
	BCV26		–	–40	V
	BCV46		–	–80	V
V <sub>CES</sub>	collector-emitter voltage	V <sub>BE</sub> = 0			
	BCV26		–	–30	V
	BCV46		–	–60	V
V <sub>EBO</sub>	emitter-base voltage	open collector	–	–10	V
I <sub>C</sub>	collector current (DC)		–	–500	mA
I <sub>CM</sub>	peak collector current		–	–800	mA
I <sub>B</sub>	base current (DC)		–	–100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	–	250	mW
T <sub>stg</sub>	storage temperature		–65	+150	°C
T <sub>j</sub>	junction temperature		–	150	°C
T <sub>amb</sub>	operating ambient temperature		–65	+150	°C

**Note**

1. Transistor mounted on an FR4 printed-circuit board.

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	500	K/W

**Note**

1. Transistor mounted on an FR4 printed-circuit board.

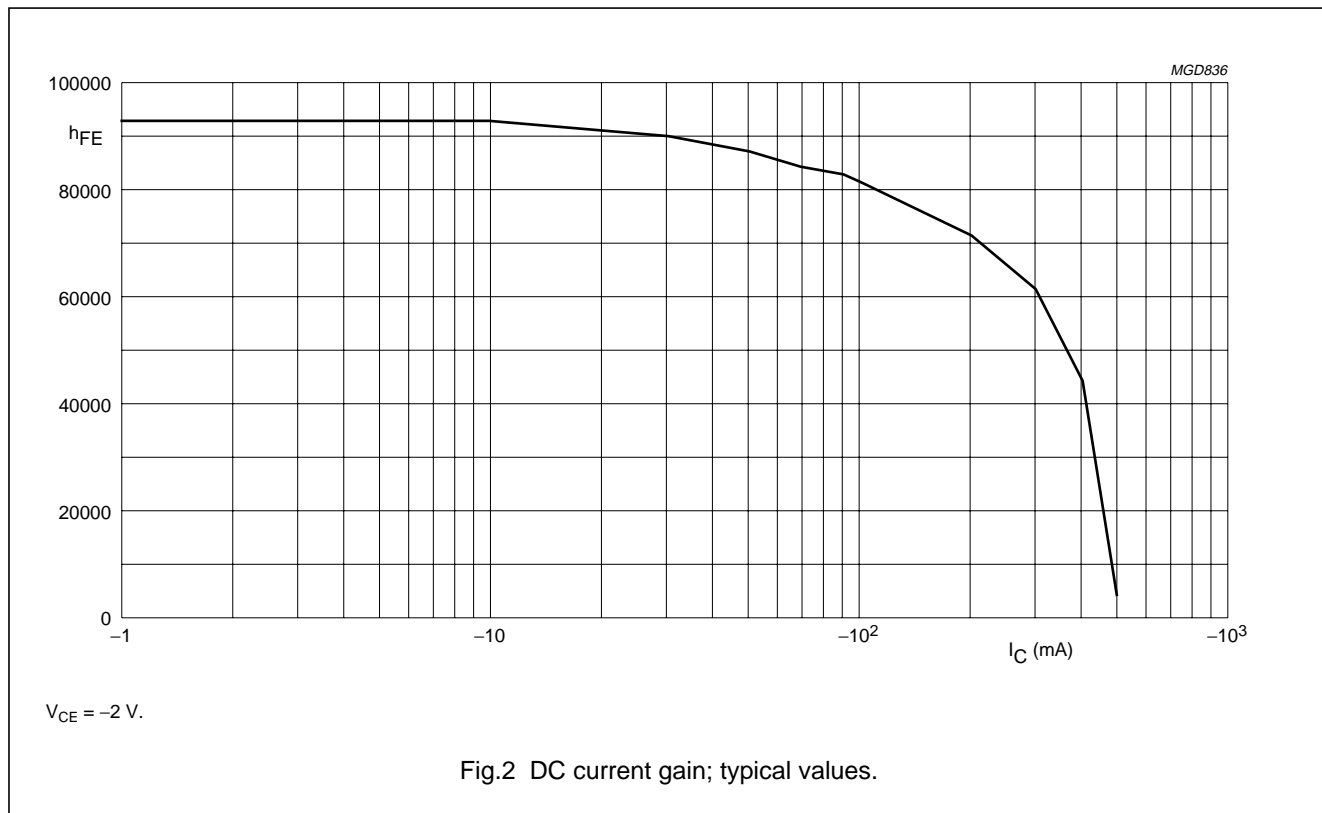
PNP Darlington transistors

BCV26; BCV46

**CHARACTERISTICS**

T<sub>amb</sub> = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current					
	BCV26	I <sub>E</sub> = 0; V <sub>CB</sub> = -30 V	-	-	-100	nA
	BCV46	I <sub>E</sub> = 0; V <sub>CB</sub> = -60 V	-	-	-100	nA
I <sub>EBO</sub>	emitter cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = -10 V	-	-	-100	nA
h <sub>FE</sub>	DC current gain					
	BCV26	I <sub>C</sub> = -1 mA; V <sub>CE</sub> = -5 V; see Fig.2	4000	-	-	
	BCV46		2000	-	-	
h <sub>FE</sub>	DC current gain					
	BCV26	I <sub>C</sub> = -10 mA; V <sub>CE</sub> = -5 V; see Fig.2	10000	-	-	
	BCV46		4000	-	-	
h <sub>FE</sub>	DC current gain					
	BCV26	I <sub>C</sub> = -100 mA; V <sub>CE</sub> = -5 V; see Fig.2	20000	-	-	
	BCV46		10000	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = -100 mA; I <sub>B</sub> = -0.1 mA	-	-	-1	V
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = -100 mA; I <sub>B</sub> = -0.1 mA	-	-	-1.5	V
V <sub>BEon</sub>	base-emitter on-state voltage	I <sub>C</sub> = -10 mA; V <sub>CE</sub> = -5 V	-	-	-1.4	V
f <sub>T</sub>	transition frequency	I <sub>C</sub> = -30 mA; V <sub>CE</sub> = -5 V; f = 100 MHz	-	220	-	MHz



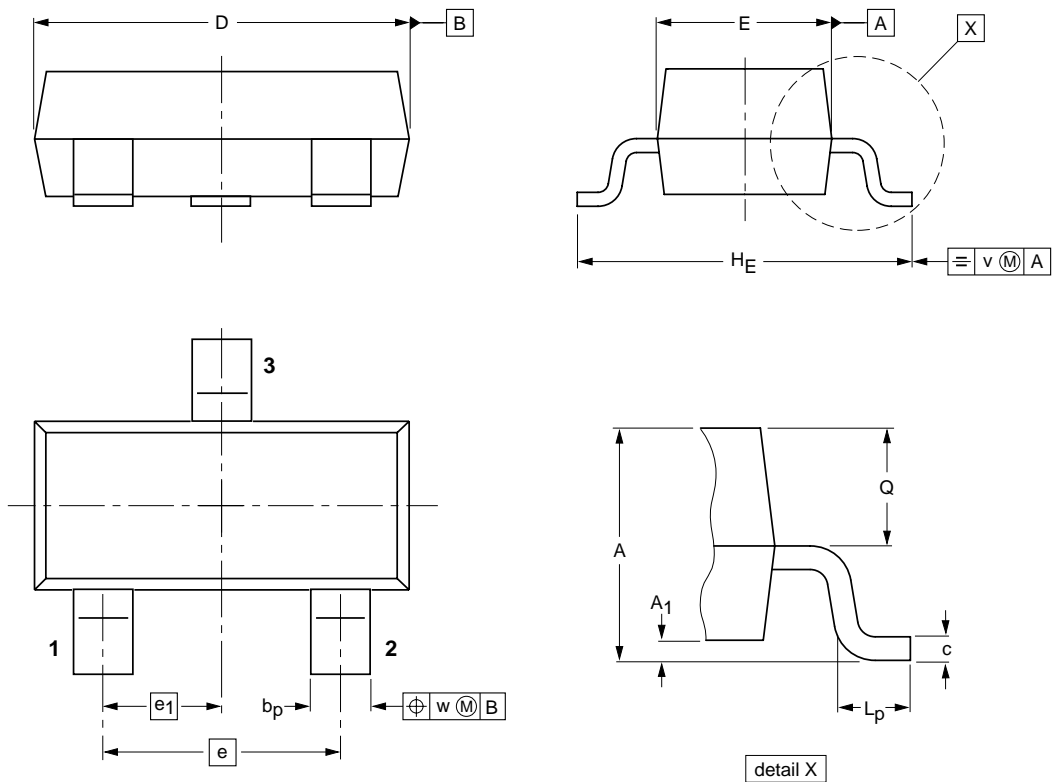
PNP Darlington transistors

BCV26; BCV46

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



DIMENSIONS (mm are the original dimensions)

UNIT	A	A <sub>1</sub> max.	b <sub>p</sub>	c	D	E	e	e <sub>1</sub>	H <sub>E</sub>	L <sub>p</sub>	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT23						97-02-28

## PNP Darlington transistors

BCV26; BCV46

**DEFINITIONS**

<b>Data Sheet Status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

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PNP Darlington transistors

BCV26; BCV46

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